



SB220 thru SB260

Schottky Barrier Rectifiers
Reverse Voltage 20 to 60 Volts Forward Current 2.0 Amperes

Features

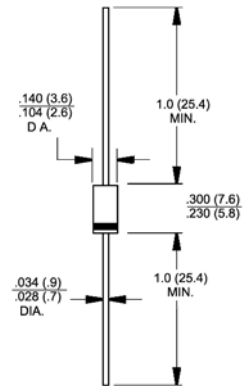
- ◆ Metal-Semiconductor junction with guard ring
- ◆ Epitaxial construction
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ The plastic material carries UL recognition 94V-0
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



DO-204AC (DO-15)

Mechanical Data

- ◆ Case : JEDEC DO-204AC(DO-15) molded plastic
- ◆ Polarity : Color band denotes cathode
- ◆ Weight : 0.014 ounce, 0.39 gram
- ◆ Mounting position : Any



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	SB220	SB230	SB240	SB250	SB260	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	Volts
Maximum average forward rectified current @T _A =75°C	I _(AV)	2.0					Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	60.0					Amps
Maximum forward Voltage at 2.0A DC Maximum forward Voltage at 1.5A DC	V _F	0.55 -			0.70 0.65		Volts
Maximum DC reverse current @T _J =25°C at rated DC blocking voltage @T _J =100°C	I _R	0.5 15.0					mA
Typical thermal resistance (Note 1)	R _{θJA}	20					°C/W
Typical junction capacitance (Note 2)	C _J	150					pF
Operating junction temperature range	T _J	-55 to +125					°C
Storage temperature range	T _{STG}	-55 to +150					°C

Notes: 1. Thermal Resistance Junction to Ambient.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

RATINGS AND CHARACTERISTIC CURVES

